

Data on sputtering and hydrogen retention of Be and Be alloy

Daiji Kato

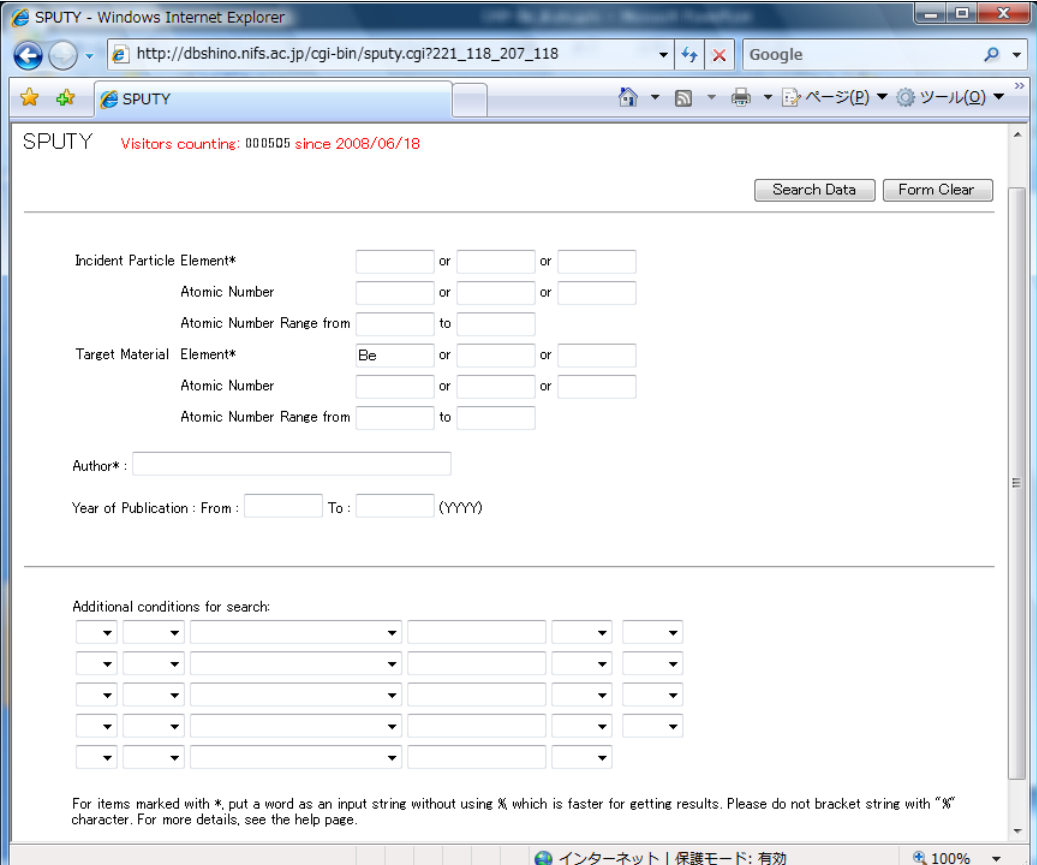
National Institute for Fusion Science

Contents

- Sputtering yield database at NIFS
 - NIFS database (SPUTY)
 - Web-site for compilation of Eckstein's TRIM.SP calculations (IPP-report)
- Review on sputtering yield data research including Japanese activities
- Review on hydrogen retention study including Japanese activities

SPUTY

sputtering yields for monoatomic solids
(amorphous target, normal incidence only)



The screenshot shows a web browser window titled "SPUTY - Windows Internet Explorer". The address bar displays the URL http://dbshino.nifs.ac.jp/cgi-bin/sputy.cgi?221_118_207_118. The page header includes the SPUTY logo and a visitor count: "Visitors counting: 000505 since 2008/06/18". Below the header are "Search Data" and "Form Clear" buttons. The main form contains search criteria for incident particles and target materials. The "Incident Particle Element*" section has input fields for element, atomic number, and atomic number range. The "Target Material Element*" section has input fields for element (pre-filled with "Be"), atomic number, and atomic number range. Below these are fields for "Author*" and "Year of Publication : From : To : (YYYY)". A section titled "Additional conditions for search:" contains five rows of dropdown menus. At the bottom, a note states: "For items marked with *, put a word as an input string without using %, which is faster for getting results. Please do not bracket string with \"%\" character. For more details, see the help page." The browser's status bar at the bottom shows "インターネット | 保護モード: 有効" and a zoom level of "100%".

SPUTY Visitors counting: 000505 since 2008/06/18

Search Data Form Clear

Incident Particle Element* or or
Atomic Number or or
Atomic Number Range from to
Target Material Element* Be or or
Atomic Number or or
Atomic Number Range from to
Author* :
Year of Publication : From : To : (YYYY)

Additional conditions for search:

For items marked with *, put a word as an input string without using %, which is faster for getting results. Please do not bracket string with \"%\" character. For more details, see the help page.

インターネット | 保護モード: 有効 100%

<http://dbshino.nifs.ac.jp>

Found Result in SPUTY - Windows Internet Explorer

http://dbshino.nifs.ac.jp/cgi-bin/sea_sputy.cgi?221_118_207_ Google

Found Result in SPUTY

[Help]

Found Result in SPUTY

Found 35 Title(s)

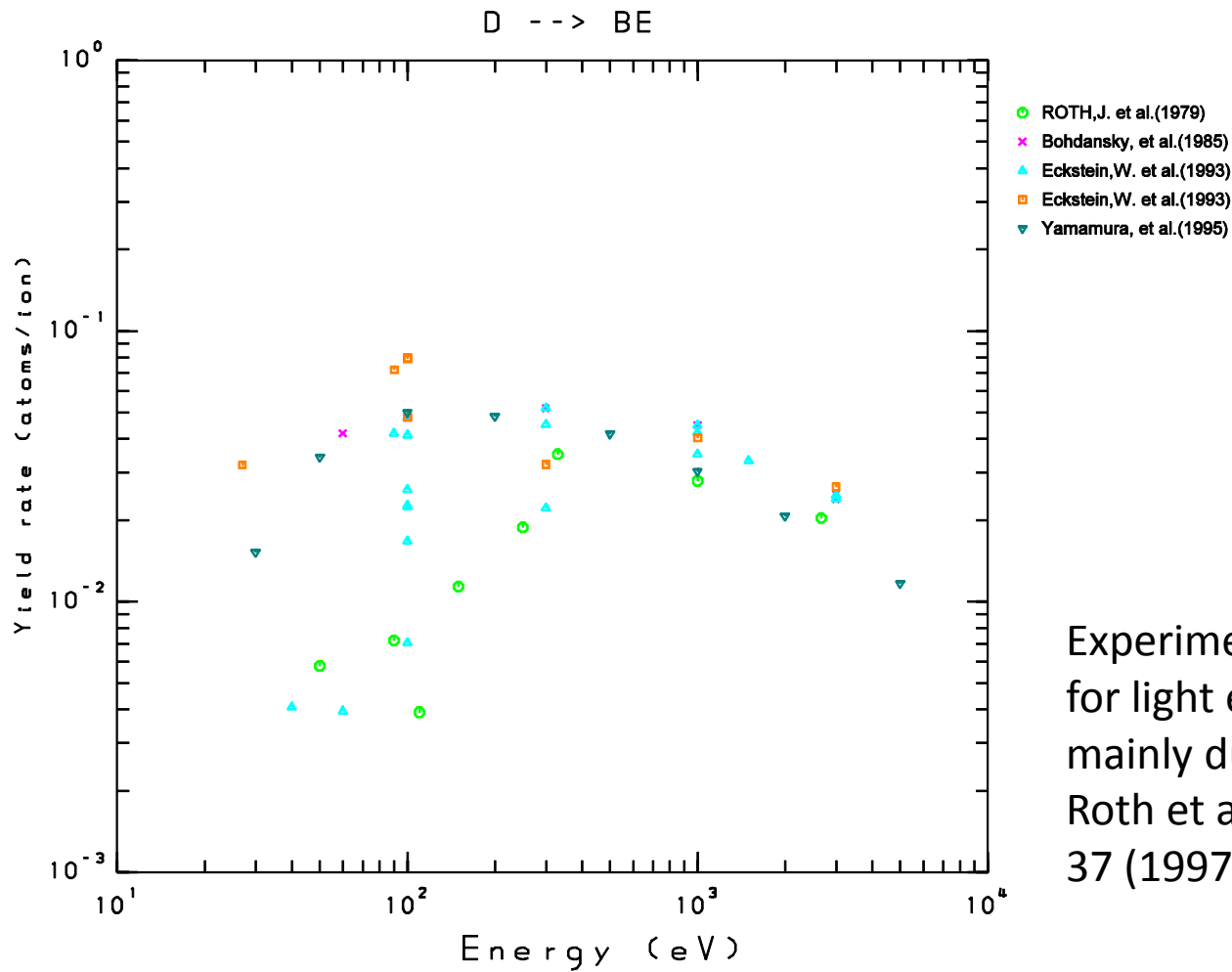
☒ All Data List 35 records found

- ☐ AR --> BE 3 records found
- ☐ BE --> BE 4 records found
- ☐ D --> BE 5 records found
- ☐ H --> BE 5 records found
- ☐ HE --> BE 6 records found
- ☐ HE-3 --> BE 1 records found
- ☐ KR --> BE 3 records found
- ☐ NE --> BE 3 records found
- ☐ O --> BE 1 records found
- ☐ T --> BE 1 records found
- ☐ XE --> BE 3 records found

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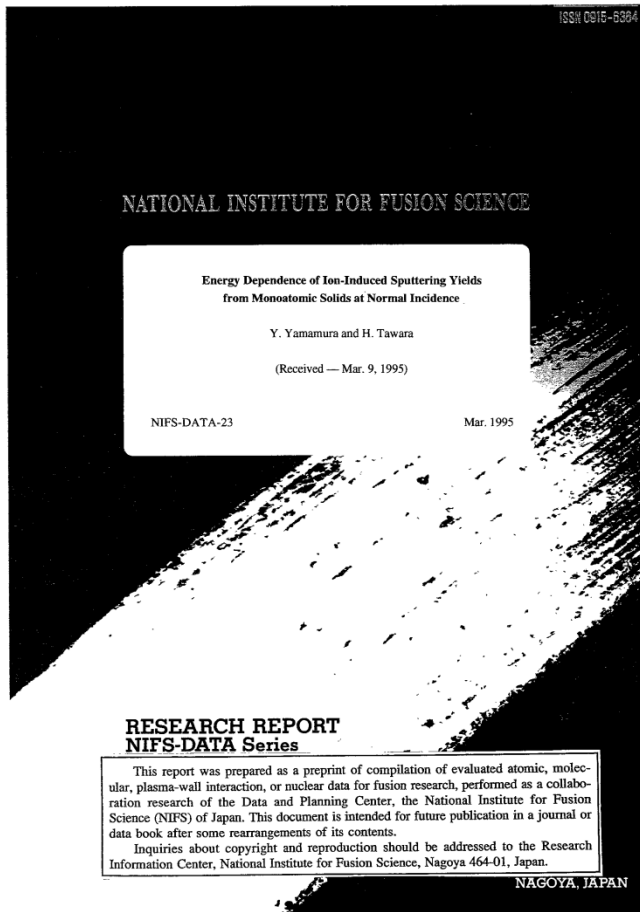
インターネット | 保護モード: 有効

100%



Experimental data are scattered for light element projectiles. It is mainly due to **surface oxidation**. Roth et al., Fusion Eng. Design 37 (1997).

NIFS-DATA-23 (1995)



ENERGY DEPENDENCE OF ION-INDUCED SPUTTERING YIELDS FROM MONOATOMIC SOLIDS AT NORMAL INCIDENCE

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National Institute for Fusion Science, Chigusa-ku
Nagoya 464-01, Japan

Abstract

The yields of the ion-induced sputtering from monoatomic solids at normal incidence for various ion-target combinations are presented graphically as a function of the incident ion energy. In order to fill the lack of the experimental data, the sputtering yields are also calculated by the Monte Carlo simulation code ACAT for some ion-target combinations. Each graph shows available experimental data points and the ACAT data, together with the sputtering yields calculated by the present empirical formula, whose parameters are determined by the best-fit to available data.

Web site of Eckstein's data compilation

http://dpc.nifs.ac.jp/DB/Eckstein/ - Windows Internet Explorer

http://dpc.nifs.ac.jp/DB/Eckstein/ アモルファス

http://dpc.nifs.ac.jp/DB/Eckstein/ ページ(P) ツール(Q)

DB-Sputtering, Reflection and Range Values

Numerical data on sputtering yield, reflection coefficients and mean range calculated by Dr. Wolfgang Eckstein using the Monte Carlo program code (TRIM.SP^[1,2]).

[1] J. P. Biersack and W. Eckstein, Appl. Phys. A **34** (1984) 73.
[2] W. Eckstein, *Computer Simulation of Ion-Solid Interactions* (Springer-Verlag, Berlin, Heidelberg, 1991)

UPDATE

4 Mar. 2003
Numerical data for **mono-atomic targets** of Cu – U, **compound targets** and **layered targets** have been up.

28 Feb. 2003
Numerical data for **mono-atomic targets** of V, Fe and Ni have been up. Contents and Representaion of Data has been revised.

26 Feb. 2003
Numerical data for **mono-atomic targets** of Al, Si and Ti have been up.

25 Feb. 2003
Numerical data for **mono-atomic target** of C have been up.

Data & Planning Center

DB-Sputtering, Reflection and Range Values

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[CONTENTS AND REPRESENTATION OF DATA](#)

[DATA TABLE](#)

Printed version:
Wolfgang Eckstein,
IPP-Report 9/132,
2002 [[PDF \(1.7MB\)](#)]

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<http://dpc.nifs.ac.jp/DB/Eckstein/>

Ion-target combinations in the database:

Monoatomic target (H,D,T,He,Be,N,O,Ne,Ar – Be)

Compound target (O – BeO)

```
% sputtering yield : D -> Be
% z1= 1, m1= 2.01, z2= 4, m2= 9.01, sbe=3.38 eV, rho=1.80 g/cm**3
% ef=0.95 eV, esb=1.00 eV, kk0=kk0r=2, kdee1=kdee2=3, ipot=ipotr=1 (KrO)
% ca=1.00
% program : trvmc, IPP 9/82
% ne=21, na=10
%
```

%	e0	0	15	30	45	55	60	65	70	75	80	85	87
%	10	4.13e-6	4.30e-6	4.56e-6									
	11	2.61e-5	3.05e-5	3.15e-5	2.69e-5	1.86e-5		1.00e-5		3.67e-6	8.00e-7	5.00e-7	
	12	9.29e-5	1.07e-4	1.25e-4	1.14e-4	8.71e-5	6.81e-5	5.37e-5		2.31e-5	1.39e-5	9.62e-6	
	13	2.32e-4	2.67e-4	3.47e-4	3.16e-4	2.61e-4	2.10e-4	1.62e-4		7.67e-5	4.78e-5	3.18e-5	
	14	4.65e-4	5.50e-4	6.90e-4	6.91e-4	5.92e-4		3.92e-4		1.91e-4	1.20e-4	7.85e-5	
	15	8.10e-4	9.42e-4	1.21e-3	1.29e-3	1.12e-3	9.82e-4	7.97e-4		4.11e-4	2.57e-4	1.65e-4	
	17	1.73e-3	2.02e-3	2.60e-3	3.03e-3	2.92e-3		2.29e-3		1.25e-3	7.67e-4	4.62e-4	
	20	3.64e-3	4.19e-3	5.46e-3	7.03e-3	7.46e-3	7.12e-3	6.59e-3		3.76e-3	2.14e-3	1.16e-3	
	25	7.30e-3	8.25e-3	1.11e-2	1.57e-2	1.87e-2	1.94e-2	1.85e-2		1.08e-2	5.51e-3	2.51e-3	
	30	1.08e-2	1.22e-2	1.69e-2	2.54e-2	3.25e-2	3.58e-2	3.46e-2		2.07e-2	1.02e-2	3.82e-3	
	40	1.68e-2	1.90e-2	2.64e-2	4.34e-2	6.08e-2		7.17e-2		4.54e-2	2.12e-2	5.91e-3	
	50	2.09e-2	2.40e-2	3.45e-2	5.78e-2	8.53e-2	9.88e-2	1.07e-1		7.40e-2	3.23e-2	7.37e-3	
	70	2.63e-2	3.04e-2	4.43e-2	7.94e-2	1.19e-1		1.60e-1		1.28e-1	5.90e-2	9.51e-3	
	100	3.10e-2	3.59e-2	5.42e-2	9.78e-2	1.49e-1	1.80e-1	2.13e-1		2.00e-1	1.01e-1	1.27e-2	
	140	3.32e-2	3.94e-2	6.11e-2	1.08e-1	1.68e-1		2.48e-1		2.71e-1	1.60e-1	1.82e-2	
	200	3.51e-2	4.03e-2	6.32e-2	1.14e-1	1.77e-1	2.20e-1	2.68e-1		3.42e-1	2.43e-1	2.93e-2	
	300	3.44e-2	4.20e-2	6.34e-2	1.12e-1	1.75e-1	2.12e-1	2.72e-1		3.91e-1	3.42e-1	5.71e-2	
	500	3.24e-2	3.85e-2	5.82e-2	1.04e-1	1.50e-1	1.98e-1	2.57e-1		4.08e-1	4.39e-1	1.38e-1	
	1000	2.53e-2	2.96e-2	4.37e-2	7.80e-2	1.25e-1	1.54e-1	2.06e-1		3.65e-1	4.59e-1	3.34e-1	
	2000	1.76e-2											
	3000	1.25e-2		2.02e-2	3.43e-2		7.29e-2		1.29e-1		2.89e-1	4.59e-1	3.18e-1

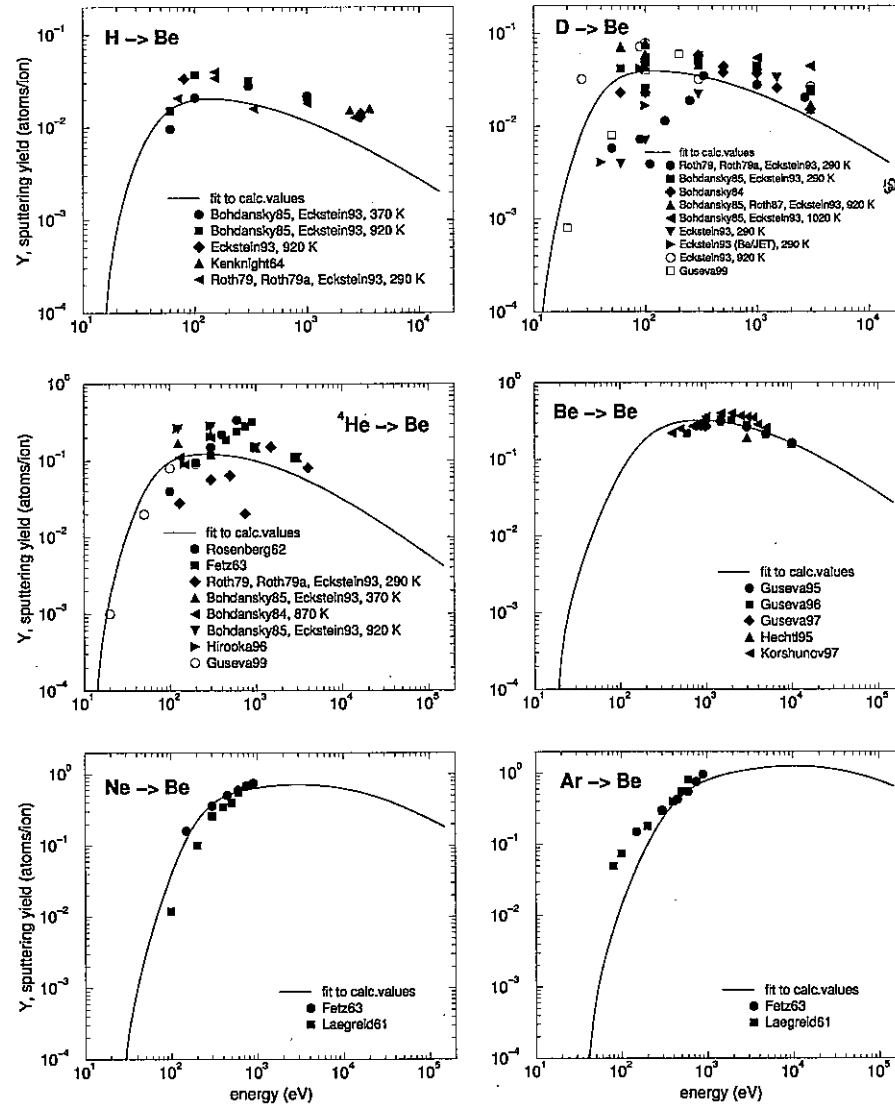


Fig. 5. Energy dependence of sputtering yields of Be for bombardment at normal incidence [47] with H [27, 48–51], D [16, 27, 48, 50–53], ^4He [16, 17, 48, 50, 51, 54–57], Be [58–62], Ne [55, 63] and Ar [55, 63]. Several authors in one line mean the same data in different publications

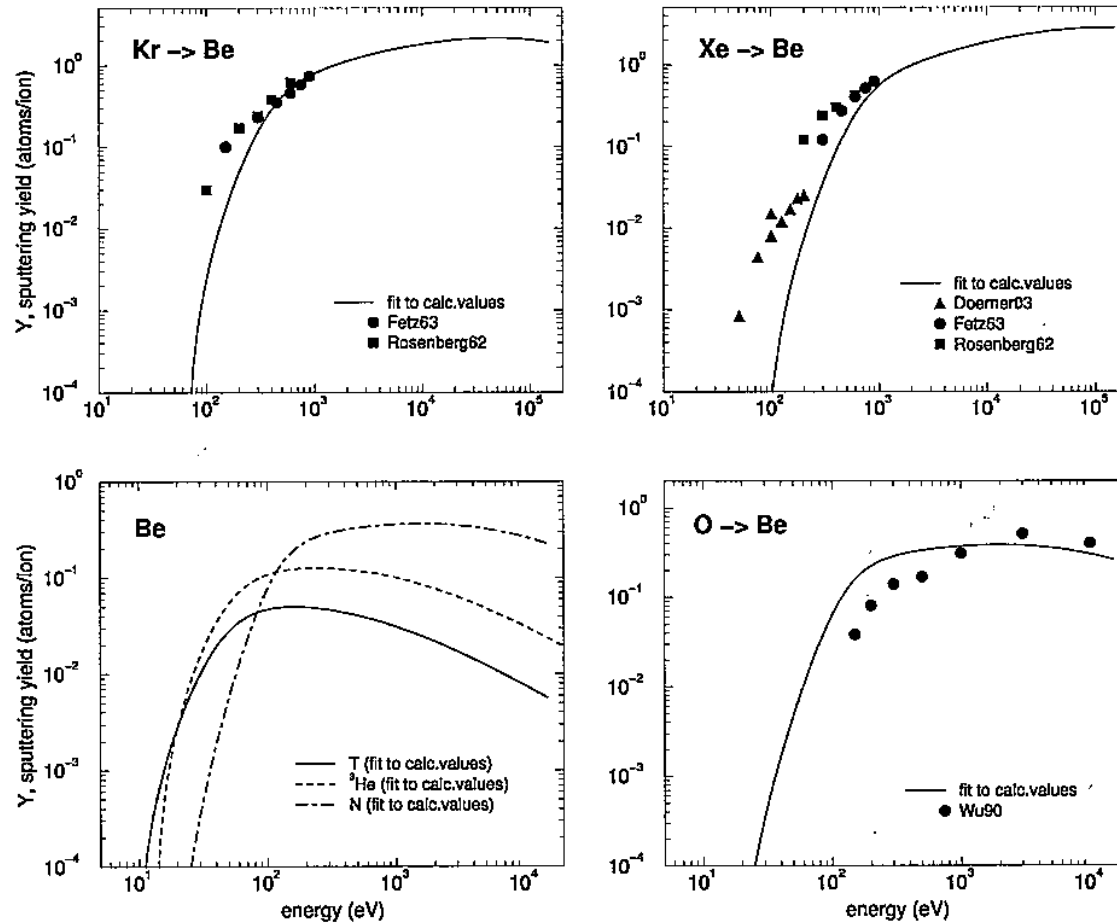


Fig. 6. Energy dependence of sputtering yields of Be for bombardment at normal incidence with Kr [54, 55], Xe [18, 54, 55], T and ^3He and N, and O [64]

Material mixing effect is significant in cases that incident particles make compound with target

Wu et al., JNM176-177 (1990)

Weight loss method

Partial sputtering yield of BeO

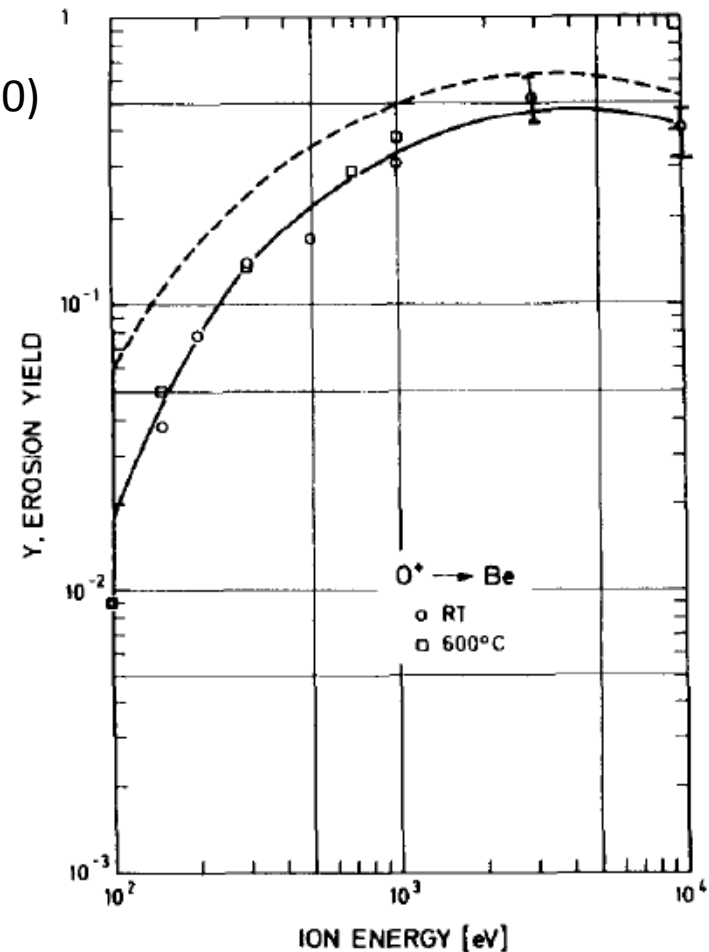
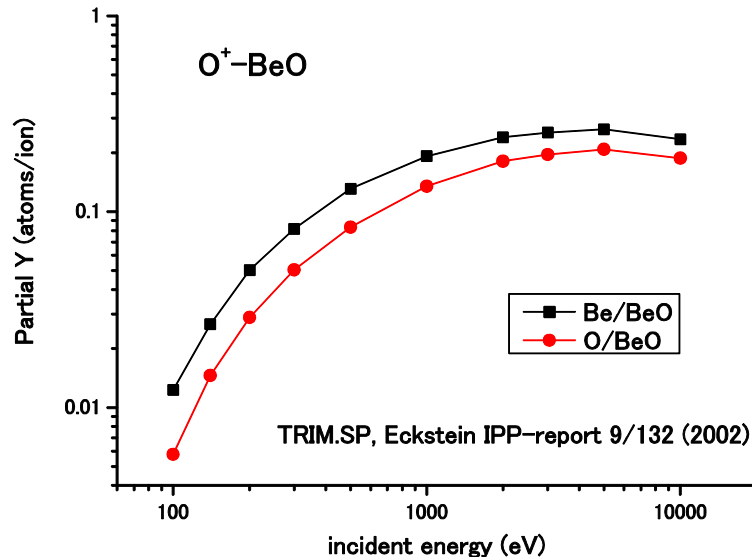


Fig. 1 The measured erosion yields of beryllium exposed to oxygen, as a function of energy: dashed line O → Be, solid line O → BeO TRIM-SP code.

Erosion of Be wall in ITER affected by co-deposition of C and W

$\text{Be}^+ \rightarrow \text{Be}, \text{Be-C}, \text{Be-W}$

Korshunov et al., JAERI-Conf. 98-001 (1998)

Weight loss method

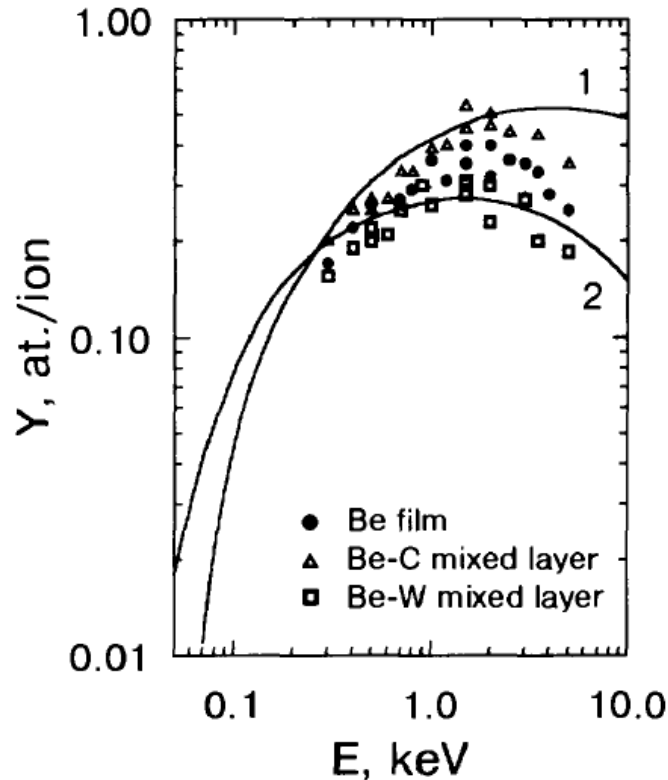


Figure 6. Experimental sputtering yield data for Be-C, Be-W mixed layers and for Be deposited films in comparison with experimental energy dependences of the self-sputtering yields for carbon (curve 1) and beryllium (curve 2).

Mixed layers co-deposited on Si substrate by simultaneous sputtering of pair targets (Be+C and Be+W).

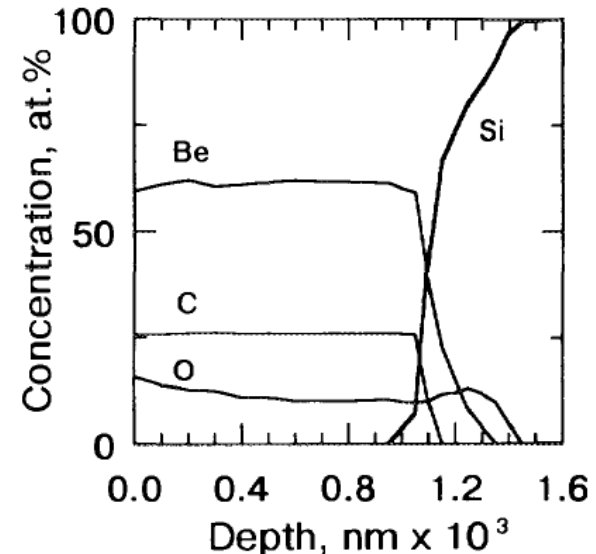
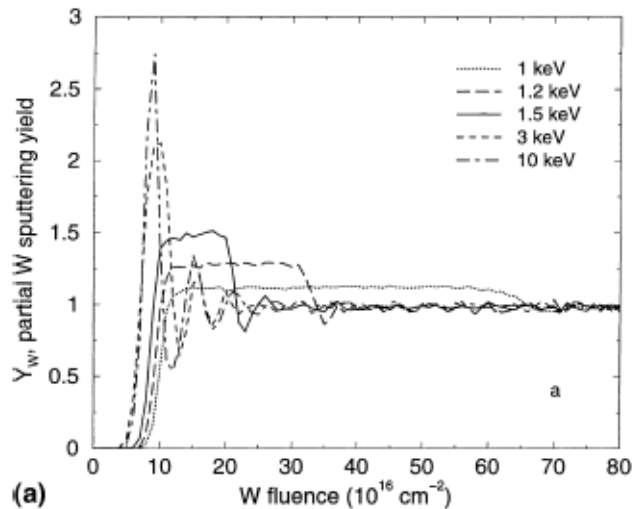


Figure 3. The depth distribution of elements in the Be-C mixed layer deposited on Si collector.

Be-D

W → Be , normal incidence



W → Be , normal incidence

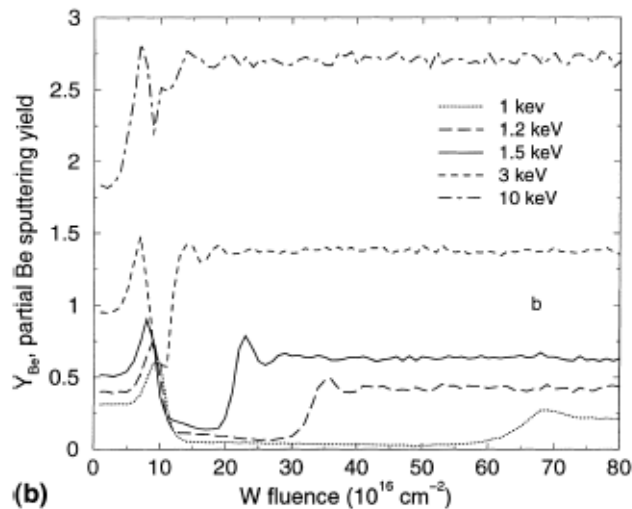
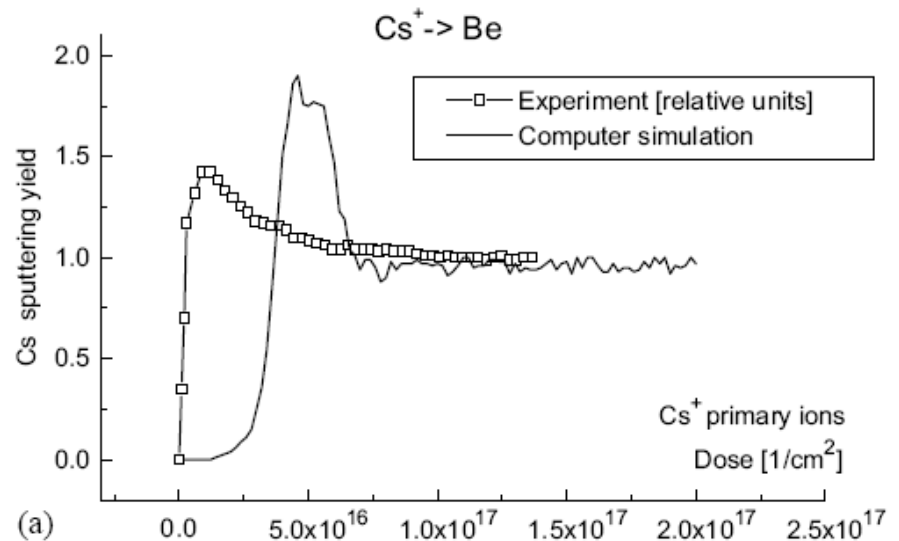


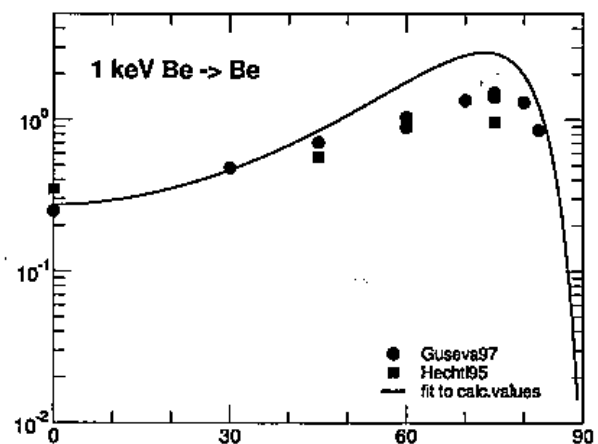
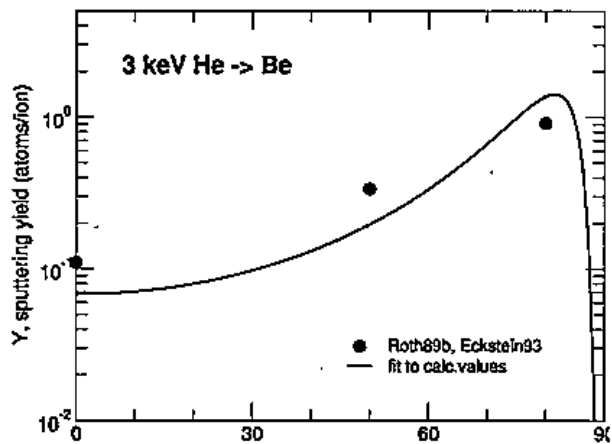
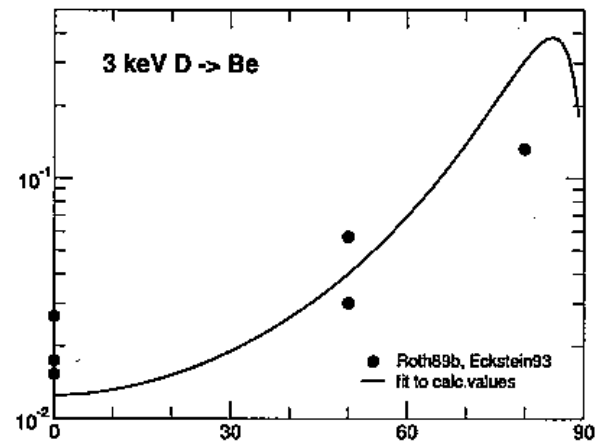
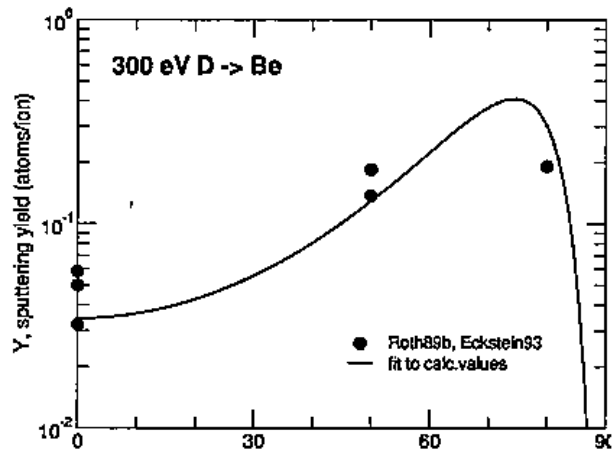
Fig. 1. Partial sputtering yields versus incident W fluence. Be is bombarded with 1, 1.2, 1.5, 3 and 10 keV W at normal incidence. (a) W partial sputtering yield, (b) Be partial sputtering yield.

Sputtering yield may depend on fluence.

Oscillatory variations of yield with fluence were predicted for light element targets bombarded by heavy projectiles, e.g. $W \rightarrow Be$. Eckstein, NIMB171 (2000).

Exp. SIMS measurement of partial sputtering yield of Cs^+ ion implanted on Be. Sielanko et al., Vacuum 70 (2003).





Incident angle

Temperature dependence of sputtering yield of Be

Radiation induced sublimation is observed. In the Figure, incident ion flux is $6 \times 10^{19} / \text{m}^2/\text{s}$. For low energy bombardment, yield enhancement is attributed to surface transition from oxide to clean Be.

Roth et al., Fusion Eng. Design 37 (1997).

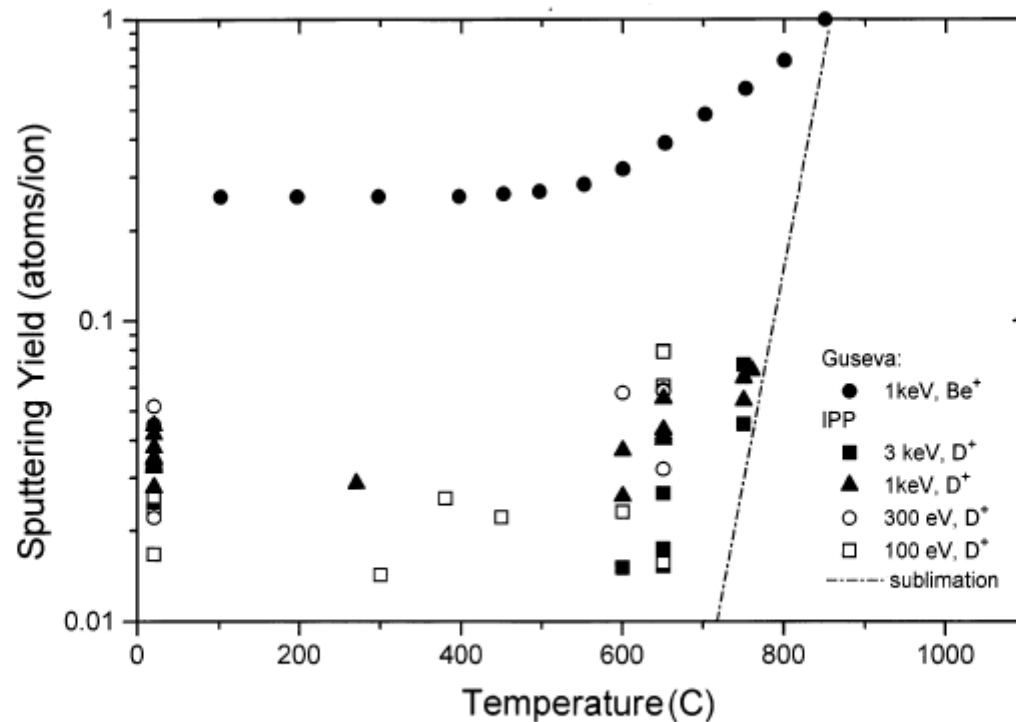


Fig. 14. Sputtering yield vs. the Be target temperature for 0.1, 0.3, 1 and 3 keV D and 1 keV Be bombardment at normal incidence [6,16,17,39].

Sputtering by multi-species impact

Besides plasma ions, impurities, e.g. C, O, metals, and coolant inert gas atoms, would affect sputtering properties.

It was found that non-recycling impurity, e.g. C, reduced erosion of Be substantially, called as “carbon poisoning”.

Roth et al., Fusion Eng. Design 37 (1997).

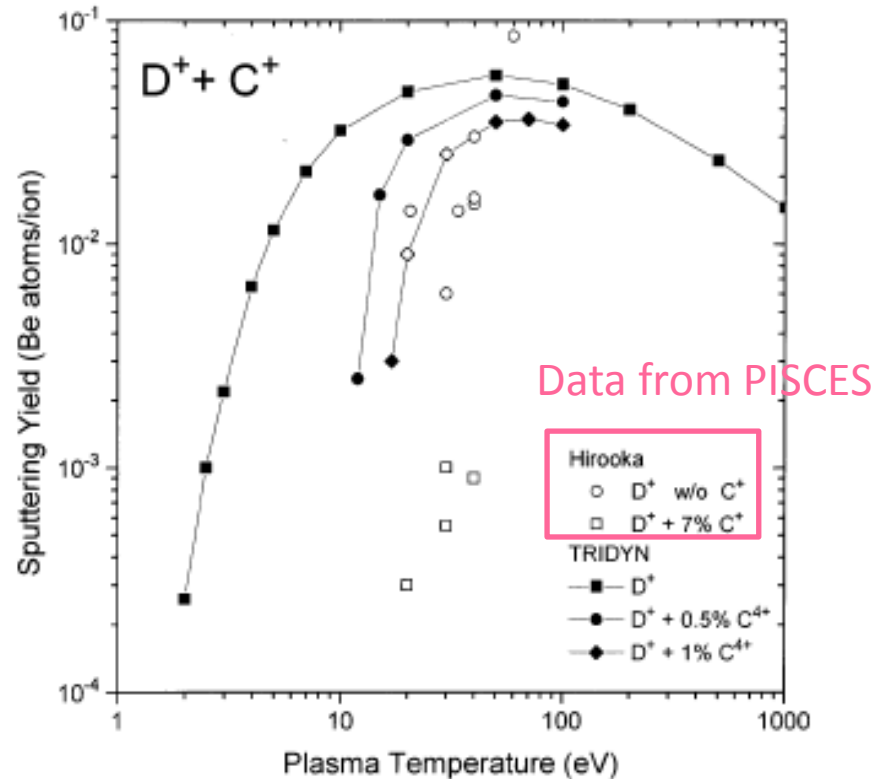


Fig. 19. Sputtering yield vs. the (electron) plasma temperature for a Maxwellian distribution of D and C projectiles bombarding Be. Experimental data for 400 eV D [25,53]. Calculated values for several impurity levels of C [38].

Available data and knowledge-base

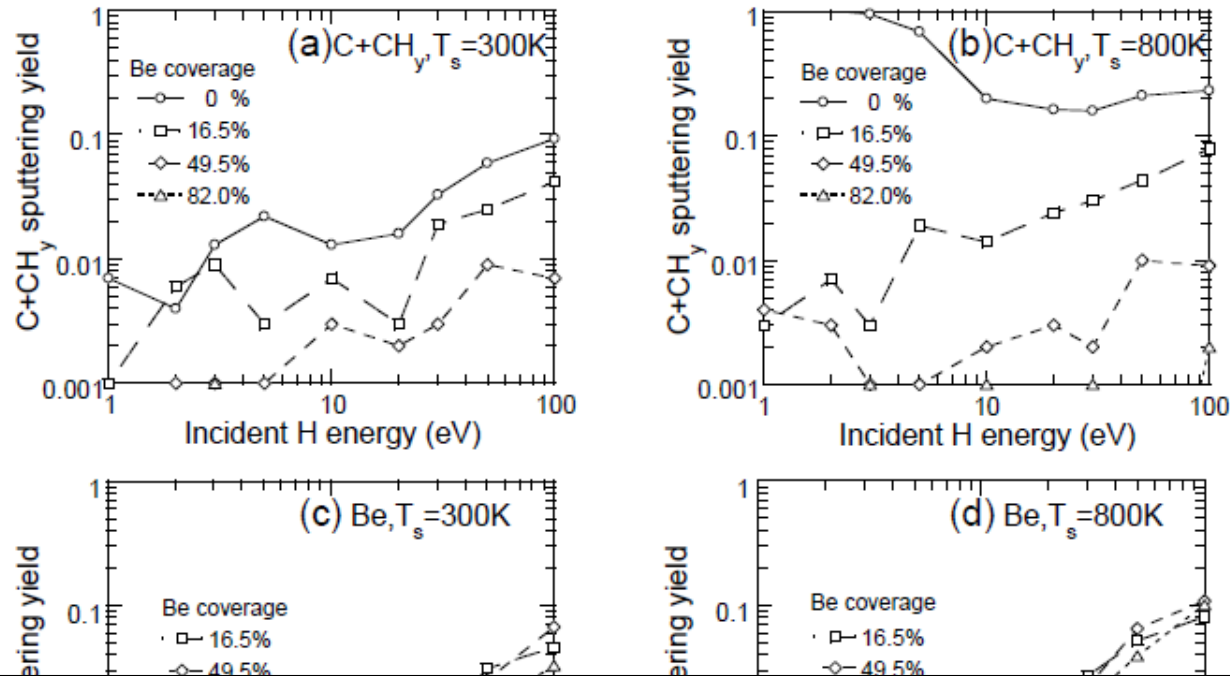
- Monoatomic and some mixed-materials targets, e.g. Be-W, Be-C, Be-O.
- Incident energy dependence (> 10 eV).
- Incident angle dependence.
- Target temperature dependence, with emphasis on surface composition change.
- Multi species-impact, with emphasis on plasma impurity effects.
- Energy-angular distribution of sputtered particles. Data can be obtained by MC simulation and Thompson formula for energy distribution for normal incidence.

Not clear, further investigation is necessary

- Low energy (< 10 eV) data.
- Energy-angular distribution of sputtered particles.
- Identification of sputtered species: atoms, molecules, clusters.
- Ro-vibration states of molecular species, electronic excited states.

Molecular dynamics simulation of erosion of a-C:H layer co-deposited with Be

Kaoru Ohya (Tokushima Univ., Japan), private communication



Erosion mitigation is attributed to formation of strong Be-C and Be-H compound at surface layers. The erosion mitigation has been observed in C targets exposed to Be-seeded plasma in PISCES-B experiment.

percentage of coverage. The target temperatures are 300 K (a and c) and 800 K (b and d).

Hydrogen isotope retention in Be

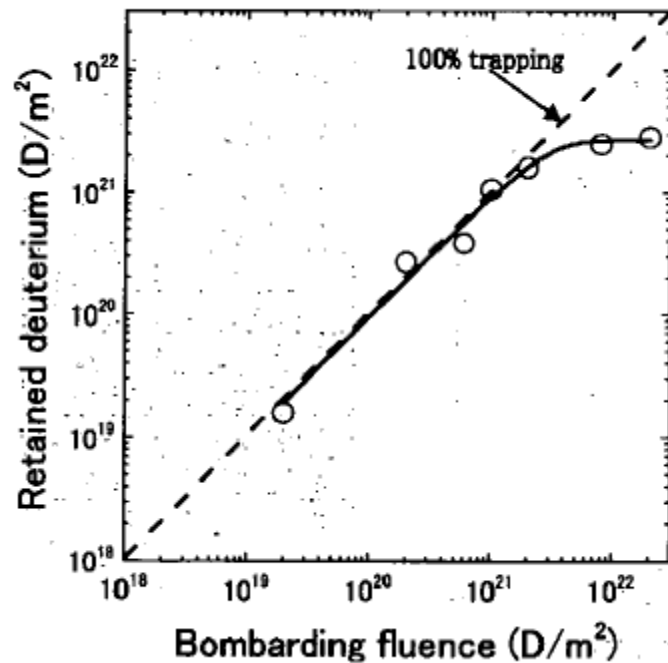
- Review by Anderl et al., JNM 273 (1999).
- Since experimental studies have been performed intensively, data are available in literatures.
- Identification of trap sites may need further investigation.
- Database development has been undertaken at NIFS, but not updated.

8 keV D_2^+ (4 keV D^+), flux $1e+18$ D/m²/s, temperature 300K

Sintered Be (Nilaco)

TDS (1K/s, 2-3 hours after implantation)

Yoshida et al., JNM233-237 (1996)



$x(D/m^2)$	$y(D/m^2)$
2.0E+19	1.6E+19
2.0E+20	2.7E+20
6.0E+20	3.8E+20
1.0E+21	1.1E+21
2.0E+21	1.6E+21
8.0E+21	2.5E+21
2.0E+22	2.8E+21

$$y = A_1 \tanh(x/A_2)$$

$$A_1 = 2.6676 \times 10^{21}$$

$$A_2 = 2.8210 \times 10^{21}$$

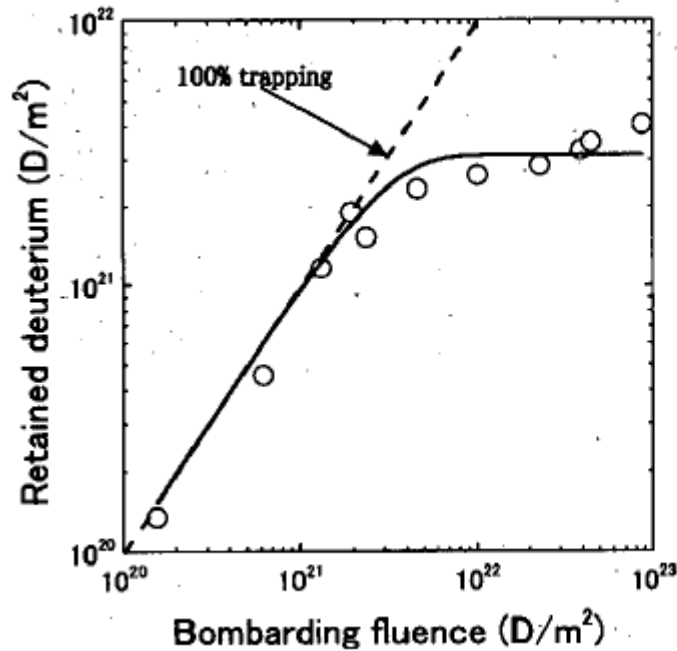
$$(x = 2 \times 10^{19} - 2 \times 10^{22} \text{ D/m}^2)$$

9 keV D⁺, flux 1e+19 D/m²/s, temperature 300K

Sintered Be (1 wt% BeO)

SIMS

Alimov et al., JNM241-243 (1997)



x(D/m ²)	y(D/m ²)
1.5E+20	1.3E+20
6.2E+20	4.6E+20
1.3E+21	1.2E+21
1.9E+21	1.9E+21
2.4E+21	1.5E+21
4.6E+21	2.3E+21
1.0E+22	2.6E+21
2.3E+22	2.8E+21
3.9E+22	3.3E+21
4.5E+22	3.5E+21
8.7E+22	4.1E+21

$$y = A_1 \tanh(x/A_2)$$

$$A_1 = 3.1282 \times 10^{21}$$

$$A_2 = 3.1735 \times 10^{21}$$

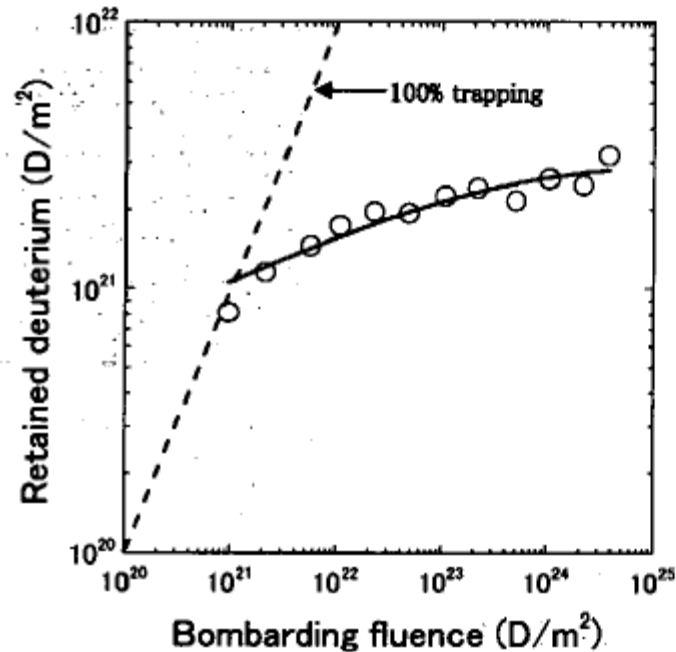
$$(x = 1 \times 10^{20} - 1 \times 10^{23} \text{ D/m}^2)$$

3 keV D_3^+ (1 keV D^+), flux $1e+20$ D/m²/s , temperature 300K

Sintered Be (Brush Wellman)

TDS (7K/s)

Haasz et al., JNM241-243 (1997)



$x(D/m^2)$	$y(D/m^2)$
9.5E+20	8.1E+20
2.1E+21	1.2E+21
5.6E+21	1.5E+21
1.1E+22	1.7E+21
2.2E+22	2.0E+21
4.8E+22	1.9E+21
1.1E+23	2.2E+21
2.2E+23	2.4E+21
5.0E+23	2.2E+21
1.0E+24	2.6E+21
2.2E+24	2.5E+21
3.8E+24	3.2E+21

$$y = A_1 \tanh(x/A_2)^p$$

$$A_1 = 2.948 \times 10^{21}$$

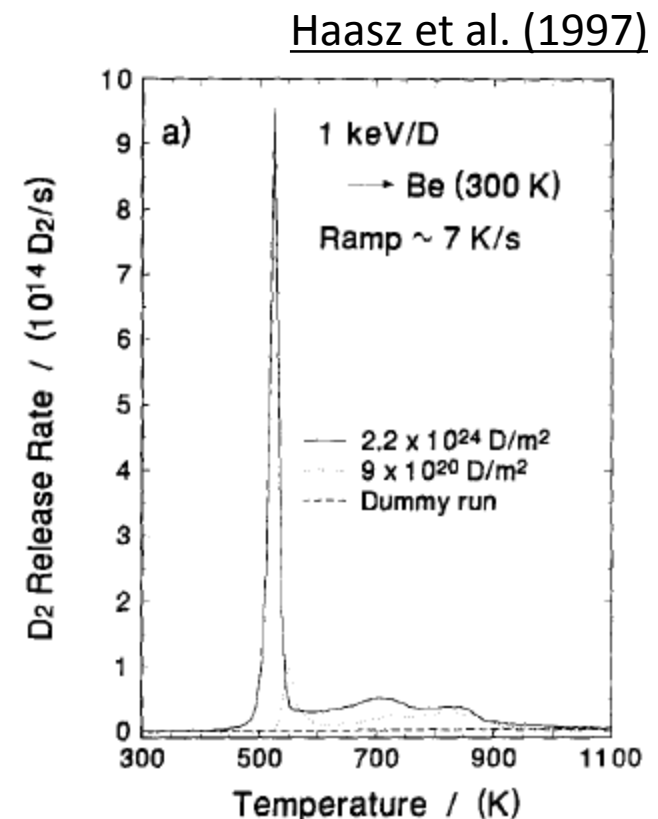
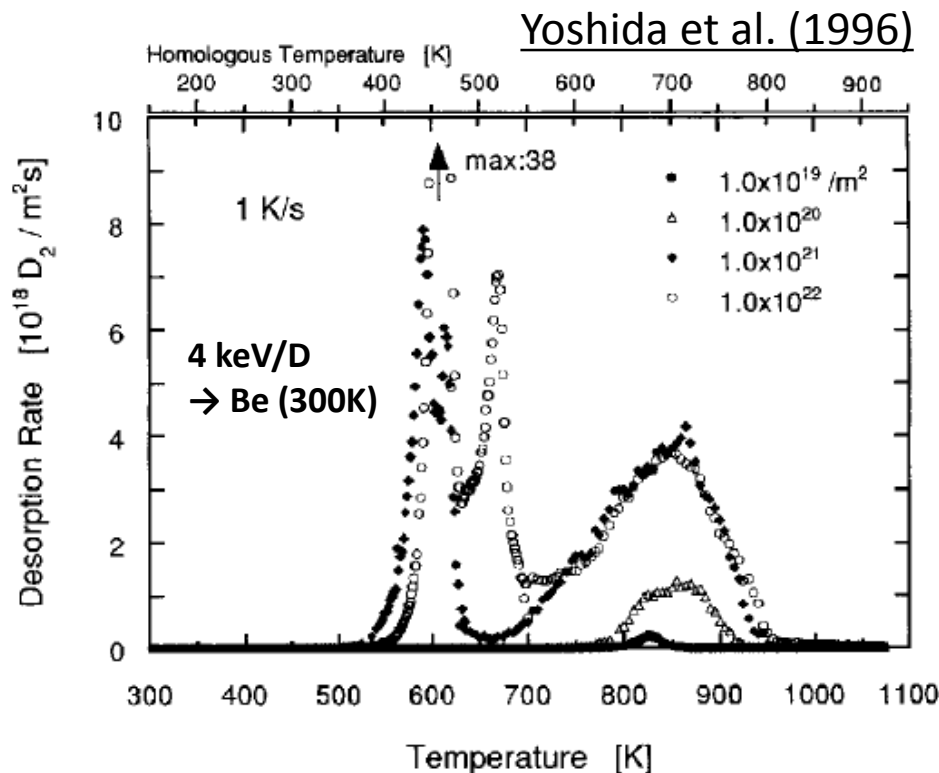
$$A_2 = 1.5085 \times 10^{23}$$

$$p = 0.19387$$

$$(x = 1 \times 10^{21} - 3 \times 10^{24} \text{ D/m}^2)$$

Typical thermal desorption spectra from Be samples bombarded by D ions at RT

Lower temperature (500-600 K) peaks are responsible for bulk of hydrogen retention at higher fluences. These peaks (disappear in high temperature above 373 K irradiations) were attributed to amorphous hydride formation in surface layers by Wilson, and to radiation damage traps or bubbles by Haasz.



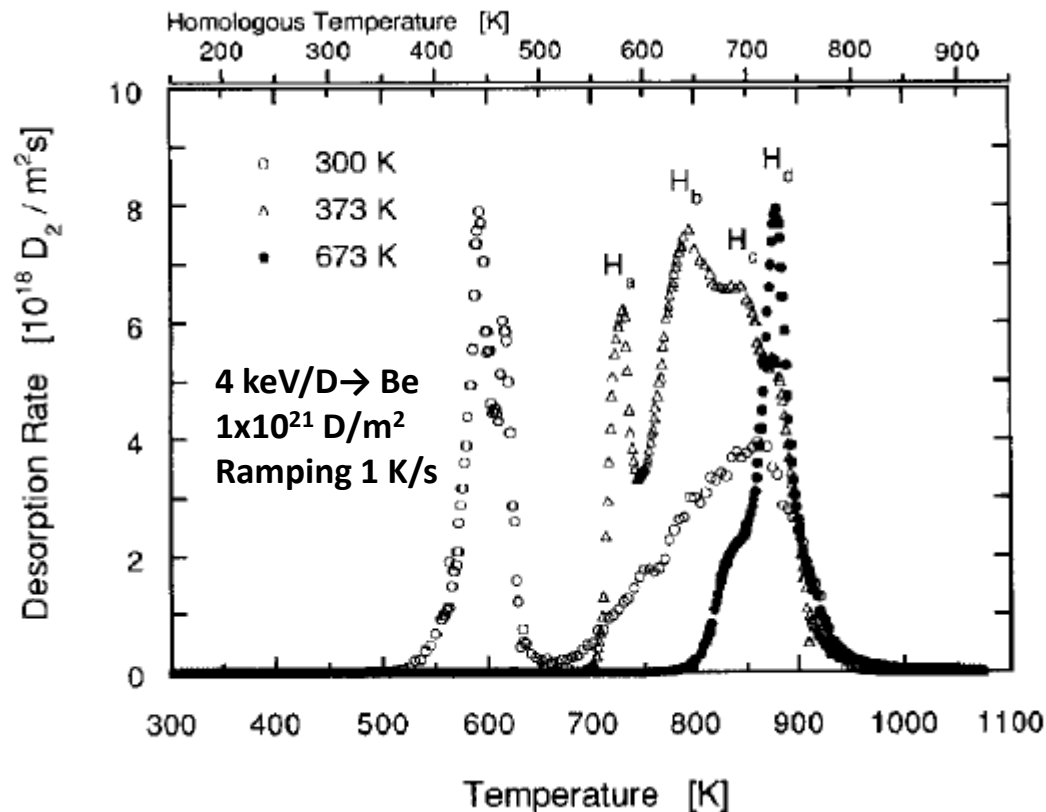
Thermal desorption spectra variation with irradiation temperature

Ha and Hb: loosely bounded to bubbles

Hc: trapped in mono-vacancy and small vacancy clusters

Hd: trapped in bubbles

Yoshida et al., JNM233-237 (1996)

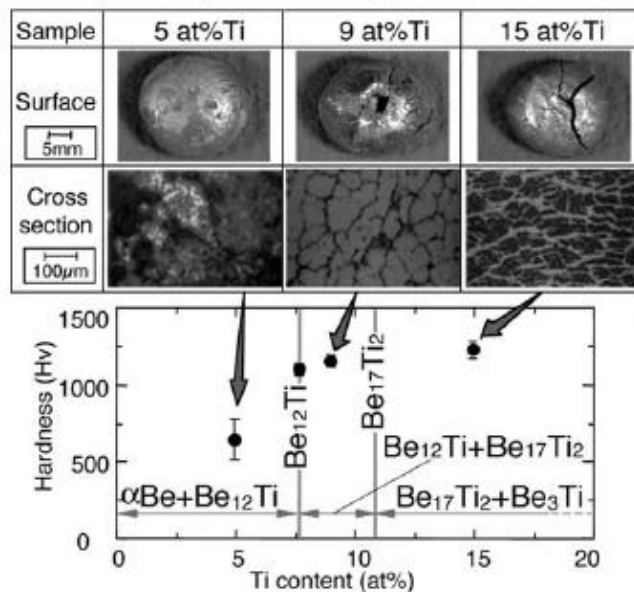


Hydrogen retention of Be alloy developed as neutron multiplier materials

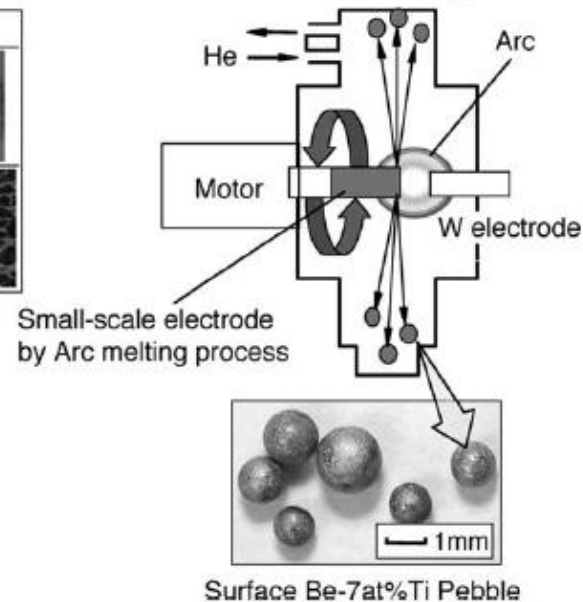
Beryllium metal has some disadvantages for high temperature (600-900 C) DEMO reactor applications, such as low melting temperature, high chemical reactivity at high temperatures.

Candidates are Be_{12}Ti , Be_{12}V and Be_{12}Mo . Ti, V, and Mo give lower radio activation and high melting temperatures. Be_{12}X structure gives good oxidation resistance and high beryllium content for the neutron multiplier.

Survey test by arc melting



Small-scale fabrication test by REM



Low hydrogen retention and desorption at lower temperature in Be₁₂Ti

Kuwamura et al., JNM329-333 (2004)

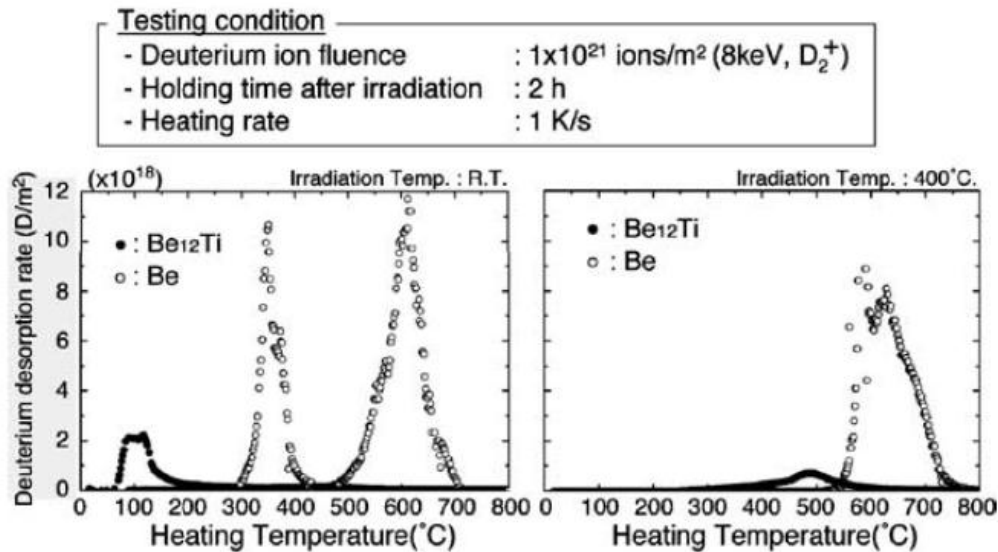


Fig. 8. Results of deuterium release test on heating of implanted Be₁₂Ti and Be.

Trapping sites in Be₁₂Ti may be small (< a few nm size) vacancy clusters and impurities.

Neutron irradiation (4×10^{24} n/m², > 1MeV, 500 C) on the Be₁₂Ti specimens has been performed at Japan Materials Testing Reactor (JMTR). Tritium inventory in n-irradiated Be₁₂Ti specimen was smaller than that in n-irradiated Be.

Mishima et al., JNM367-370 (2007).

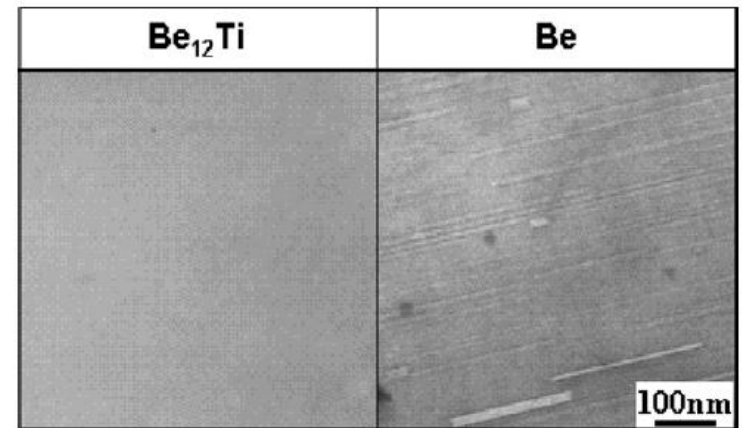


Fig. 6. Transmission-electron micrograph of Be₁₂Ti and beryllium irradiated with 8 keV-D₂⁺ to dose of 2×10^{21} D⁺/m² at 400 °C.

Hydrogen isotope retention data research activities in Japan

- Be alloy for blanket materials development will be studied intensively in ITER-BA (centered at IFERC, Rokkasho, Aomori).
- Neutron irradiation effects (knock-on defect, helium transmutation) are key issues in future studies.
- Simulation studies on radiation induced microstructure development and hydrogen trapping are encouraged.